L Number	Hits	Search Text	DB	Time stamp
-	100	("5578862"	USPAT;	2003/03/27
		"6013950"	US-PGPUB;	16:55
		"4338571"	EPO; JPO;	
		"4898837"	DERWENT	
		"5221857"		
1		"5583058"		
		"5587612"		
		"5633190"		
		"5858850"		
		"5252502"		
		"4475955"		
		"4495222"	1	
		"4499557"		
		"4560422"		
		"4600658"		
İ		"4971926"		
		"5320932"		
		"5329155"		
		"5502327"		
		"5668755"		
]		"5670819"		
		"5751050"		
		"5821587"		
		"5970338"		·
		"6031266"		
		"6124615"		
		"6229190"		
		"6242792"		
		"6445055"		
1		"4259564"		
		"4326213"		
		"4609935"		
		"4782202"		
		"4947020"		
		"5276346"		
		"5356826"		
		"5391906"		
		"5436483"	•	
		"5436484"	•	
		"5534723"		
1		"5610089"		
		"5618749"		
		"5963279"		
		"4265117"		
		"4620212"		
		"4626881"		
		"4755480"		,
1		"4786612"		
		"4847783"		
		"4975386").pn.	-	
			IICDAM:	2002/11/17
1-	257	((resistor or gate) with sti) same active	USPAT;	2003/11/17
			US-PGPUB;	15:15
			EPO; JPO;	
1	100	//wastabay on makely sith white sites	DERWENT	2003/03/27
-	189	((resistor or gate) with sti) with active	USPAT;	
			US-PGPUB;	17:00
			EPO; JPO;	
	37	///wasistan on mata) with stil with	DERWENT	2003/03/27
-	37	, , ,	USPAT;	2003/03/27 17:56
		active	US-PGPUB;	1,1,20
) and 257/62 gglg and 6ad-20010205	EPO; JPO;	
	192) and 257/\$3.ccls. and @ad<20010305 resistor with (dielectric or insulator)	DERWENT USPAT;	2003/03/27
-	192	with active	US-PGPUB;	18:46
		with active		1 20.40
			EPO; JPO;	
1	i		DERWENT	i l

			· · · · · · · · · · · · · · · · · · ·	
-	28	(resistor with (dielectric or insulator) with active	USPAT; US-PGPUB; EPO; JPO;	2003/03/27
-	12) and 257/\$3.ccls. and @ad<20010305 ("3574932" "4179310" "4468414" "4594265" "4704188" "4708747" "4839711" "5179434" "5367284" "5414404" "5525831" "6316325"	DERWENT USPAT	2003/03/27 18:38
_	52	"2001/0017397").PN. resistive with (dielectric or insulator) with active	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/27 18:46
-	8	(resistive with (dielectric or insulator) with active	USPAT; US-PGPUB; EPO; JPO;	2003/03/27 18:47
-	2178) and 257/\$3.ccls. and @ad<20010305 resistor with (over or under) with (dielectric or insulat\$3)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/03/31 17:19
-	86	(resistor with (over or under) with (dielectric or insulat\$3)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/03/31 14:15
_	74) same active ((resistor with (over or under) with (dielectric or insulat\$3)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/03/31 17:24
_	204) same active) and @ad<20010305 (resistor with (over or under) with (dielectric or insulat\$3)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/03/31 16:53
) and (width with resistance)	DERWENT	
-	12	<pre>((resistor with (over or under) with (dielectric or insulat\$3)) same active) and (width with resistance)</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 16:59
_	9	((resistor with (over or under) with (dielectric or insulat\$3)) same active) and dummy	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 16:59
-	3	<pre>((resistor with (over or under) with (dielectric or insulat\$3)) same active) and (distance with between with resistors)</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:20
_	105	(resistor with (over or under) with (dielectric or insulat\$3)	USPAT; US-PGPUB; EPO; JPO;	2003/03/31 17:46
) and (distance with between with resistors)	DERWENT	
_	94	((resistor with (over or under) with (dielectric or insulat\$3)	USPAT; US-PGPUB; EPO; JPO;	2003/03/31 17:24
) and (distance with between with resistors)	DERWENT	
L	<u> </u>) and @ad<20010305	L	1

-	3	(USPAT;	2003/03/31
		active same (insulator or dielectric)	US-PGPUB;	17:51
			EPO; JPO;	
İ			DERWENT	
-	4	(dummy adj gate) and (resistor same	USPAT;	2003/03/31
		active same (insulator or dielectric))	US-PGPUB;	17:51
1			EPO; JPO;	
			DERWENT	
_	2	(resistor with over with sti) same active	USPAT;	2003/03/31
			US-PGPUB;	17:58
			EPO; JPO;	
			DERWENT	
<u>-</u>	l 8	(resistor with sti) same active	USPAT;	2003/03/31
		·	US-PGPUB;	17:58
			EPO; JPO;	
			DERWENT	
_	l o	jp-9022641-\$.did.	USPAT;	2003/11/17
) p 3022012 4.020.	US-PGPUB;	16:08
ŀ			EPO; JPO;	
ľ			DERWENT	
_	۱ ،	jp-90022641-\$.did.	USPAT;	2003/11/17
		JP 30022011	US-PGPUB;	16:09
	1		EPO; JPO;	
			DERWENT	
1_	1	jp-3227060-\$.did.	USPAT;	2003/11/17
		JP 3227000 V. ata.	US-PGPUB;	17:08
			EPO; JPO;	17.00
			DERWENT	
_	8314	transistor with common with source with	USPAT;	2003/11/17
	0314	drain	US-PGPUB;	17:09
		drain	EPO; JPO;	17.09
			DERWENT	
	711	transistor with common with source with	l	2003/11/17
-	/11		USPAT;	18:04
		drain with series	US-PGPUB;	18:04
			EPO; JPO;	
		/ h	DERWENT	2002/11/17
-	50	(USPAT;	2003/11/17
	•	drain with series) same insulat\$3	US-PGPUB;	17:13
			EPO; JPO;	
	4.6	//	DERWENT USPAT:	2003/11/17
-	46	1 ' '		18:32
	ļ	drain with series) same insulat\$3	US-PGPUB;	10:32
1		\ and @ad<20010305	EPO; JPO;	l i
	10404) and @ad<20010305	DERWENT	2002/11/17
1-	12404	transistor with coupled with series	USPAT;	2003/11/17
			US-PGPUB;	18:05
]		EPO; JPO;	
	1000	bushed ston with rounded with south a 185	DERWENT	2002/11/17
-	1589	transistor with coupled with series with	USPAT; US-PGPUB;	2003/11/17
		source with drain		18:11
			EPO; JPO;	
	_	/manual manual manual and and and a contract of the contract o	DERWENT	2003/11/17
-	2		USPAT;	2003/11/17
		source with drain	US-PGPUB;	18:12
		\ d 057/4011-	EPO; JPO;	
	_) and 257/401.ccls.	DERWENT	2002/11/17
-	l 7	(transistor with coupled with series	USPAT;	2003/11/17
) 057/401 - 3	US-PGPUB;	19:11
) and 257/401.ccls.	EPO; JPO;	
		257/401 3	DERWENT	2002/11/17
-	1233	257/401.ccls.	USPAT;	2003/11/17
			US-PGPUB;	18:32
			EPO; JPO;	
			DERWENT	
-	79	257/401.ccls. and (shar\$3 with source	USPAT;	2003/11/17
		with drain)	US-PGPUB;	18:36
			EPO; JPO;	
			DERWENT	
-	73	(257/401.ccls. and (shar\$3 with source	USPAT;	2003/11/17
		with drain)) and @ad<20010305	US-PGPUB;	19:12
			EPO; JPO;	
	l .		DERWENT	

	2	257/401.ccls. and ((shar\$3 with source	USPAT;	2003/11/17
-		with drain) same trench)	US-PGPUB;	18:38
		,	EPO; JPO;	
			DERWENT	0000/11/17
-		(transistor with coupled with series with source with drain	USPAT; US-PGPUB;	2003/11/17 18:38
		Source with drain	EPO; JPO;	10.50
) same sti	DERWENT	
-	2		USPAT;	2003/11/17
			US-PGPUB;	18:39
) same sti	EPO; JPO; DERWENT	
_	1	(transistor with coupled with series	USPAT;	2003/11/17
	-		US-PGPUB;	18:40
) same (shallow adj trench)	EPO; JPO;	
	20	(shallow adj trench) same (source with	DERWENT USPAT;	2003/11/17
-	20	drain with series)	US-PGPUB;	18:50
			EPO; JPO;	
			DERWENT	0000/11/15
-	27		USPAT; US-PGPUB;	2003/11/17 18:51
		drain with coupled)	EPO; JPO;	10.31
			DERWENT	
-	12		USPAT;	2003/11/17
İ	1	drain with coupled)) and @ad<20010305	US-PGPUB;	18:51
			EPO; JPO; DERWENT	
_	10238	form\$3 with resistor with insulat\$3	USPAT;	2003/11/17
	10230	TOTAL HILL TODIOGE HILL ENGALEST	US-PGPUB;	19:04
			EPO; JPO;	
		(burned than with the same less with the same less	DERWENT	2003/11/17
-	44	(transistor with coupled with series	USPAT; US-PGPUB;	19:10
) and (form\$3 with resistor with	EPO; JPO;	
	1	insulat\$3)	DERWENT	
-	122765	(source or drain or active) with (shallow	USPAT;	2003/11/17
	[or sti or resistor)	US-PGPUB; EPO; JPO;	19:11
	1		DERWENT	
_	752	(form\$3 with resistor with insulat\$3)	USPAT;	2003/11/17
1		same ((source or drain or active) with	US-PGPUB;	19:11
		(shallow or sti or resistor))	EPO; JPO; DERWENT	
_	1	((form\$3 with resistor with insulat\$3)	USPAT;	2003/11/17
	1	same ((source or drain or active) with	US-PGPUB;	19:11
		(shallow or sti or resistor))) and	EPO; JPO;	
		257/401.ccls.	DERWENT USPAT;	2003/11/17
-	259	((form\$3 with resistor with insulat\$3) same ((source or drain or active) with	USPAT; US-PGPUB;	19:40
		(shallow or sti or resistor))) and	EPO; JPO;	
		257/\$3.ccls.	DERWENT	
-	225	(((form\$3 with resistor with insulat\$3)	USPAT;	2003/11/17 19:58
		same ((source or drain or active) with (shallow or sti or resistor))) and	US-PGPUB; EPO; JPO;	19.30
		257/\$3.ccls.) and @ad<20010305	DERWENT	
-	15	form\$3 with resistor with over with	USPAT;	2003/11/17
		(shallow or sti)	US-PGPUB;	19:24
			EPO; JPO; DERWENT	
_	105	form\$3 with resist\$4 with over with	USPAT;	2003/11/17
		(shallow or sti)	US-PGPUB;	19:24
			EPO; JPO;	
	3.1	/formed with resisted with area with	DERWENT USPAT;	2003/11/17
-	31	(form\$3 with resist\$4 with over with (shallow or sti)) and 257/\$3.ccls.	US-PGPUB;	19:58
		Condition of Seri, and Est, 43. corp.	EPO; JPO;	
			DERWENT	
-	2	transistor same coupled same series same	USPAT;	2003/11/17
		shallow same trench	US-PGPUB; EPO; JPO;	19:40
			DERWENT	
L	1			<u> </u>

Page 4

			,	
-	14	(source or drain) same coupled same series same shallow same trench	USPAT; US-PGPUB; EPO; JPO;	2003/11/17 19:39
_	71	transistor same coupled same shallow same	DERWENT USPAT;	2003/11/17
		trench	US-PGPUB; EPO; JPO; DERWENT	19:40
_	30	(transistor same coupled same shallow same trench) and 257/\$3.ccls.	USPAT; US-PGPUB; EPO; JPO;	2003/11/17 19:57
-	13	"5477484" "5703820" "5745401" "5787033" "5866457" "5930180" "6084794" "6136648" "6236587"	DERWENT USPAT	2003/11/17 19:43
_	13	"6363001" "2002/0060347").PN. ("4426686" "5117389" "5329483" "5477484" "5703820" "5745401" "5787033" "5866457" "5930180" "6084794" "6136648" "6236587" "6363001" "2002/0060347").PN.	USPAT	2003/11/17 19:51
-	193		USPAT; US-PGPUB; EPO; JPO;	2003/11/17 20:18
-	73	(dielectric and isolation and bit and word and rom and node and diffusion) and 257/\$3.ccls.	DERWENT USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:58
-	59	((dielectric and isolation and bit and word and rom and node and diffusion) and 257/\$3.ccls.) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:24
-	2	(word adj line) with over with (dielectric adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 . 20:09
-	13	(word adj line) with over with (shallow adj trench)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:09
-	9	((word adj line) with over with (shallow adj trench)) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:13
_	49	poplevine.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:13
_	0	(dielectric adj isolation) with resistor with node	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:18
-	10	(dielectric adj isolation) with resistor with over	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:20
-	7	(fox) with resistor with over	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:22
-	5	sti with resistor with over	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:23
-	37	trench with resistor with over	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:23

-	27		USPAT;	2003/11/17
		@ad<20010305	US-PGPUB;	20:31
	1		EPO; JPO;	
			DERWENT	
-	44	(shallow adj trench) with separated with	USPAT;	2003/11/17
		active with regions	US-PGPUB;	20:55
		-	EPO; JPO;	
			DERWENT	
-	23	((shallow adj trench) with separated with	USPAT;	2003/11/17
		active with regions) and @ad<20010305	US-PGPUB;	20:31
			EPO; JPO;	
			DERWENT	
-	9	("5429956" "5434093" "5538913"	USPAT	2003/11/17
		"5677218" "5686321" "5698461"		20:37
		"5712501" "5712503" "5766998").PN.		
-	15	((shallow adj trench) with active with	USPAT;	2003/11/17
	1	regions) same resistor	US-PGPUB;	20:47
			EPO; JPO;	
			DERWENT	
-	478	isolation with separated with active with	USPAT;	2003/11/17
		regions	US-PGPUB;	20:55
			EPO; JPO;	
			DERWENT	
-	7	isolation with separated with active with	USPAT;	2003/11/17
		regions with resistor	US-PGPUB;	20:57
			EPO; JPO;	
1			DERWENT	
-	0	653108.apn.	USPAT;	2003/11/17
	1		US-PGPUB;	20:57
			EPO; JPO;	
			DERWENT	